Yung-Chen Lin

List of Publications by Year in descending order

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471509 642732 2,942 26 17 23 citations h-index g-index papers 27 27 27 4432 docs citations times ranked citing authors all docs

#	Article	IF	Citations
1	High-speed graphene transistors with a self-aligned nanowire gate. Nature, 2010, 467, 305-308.	27.8	1,156
2	High-frequency self-aligned graphene transistors with transferred gate stacks. Proceedings of the National Academy of Sciences of the United States of America, 2012, 109, 11588-11592.	7.1	312
3	High- $\langle i \rangle^{\Omega} \langle i \rangle$ oxide nanoribbons as gate dielectrics for high mobility top-gated graphene transistors. Proceedings of the National Academy of Sciences of the United States of America, 2010, 107, 6711-6715.	7.1	187
4	Sub-100 nm Channel Length Graphene Transistors. Nano Letters, 2010, 10, 3952-3956.	9.1	167
5	Single Crystalline PtSi Nanowires, PtSi/Si/PtSi Nanowire Heterostructures, and Nanodevices. Nano Letters, 2008, 8, 913-918.	9.1	166
6	Top-Gated Graphene Nanoribbon Transistors with Ultrathin High- <i>k</i> Dielectrics. Nano Letters, 2010, 10, 1917-1921.	9.1	160
7	Unveiling the Formation Pathway of Single Crystalline Porous Silicon Nanowires. ACS Applied Materials & ACS Applied & ACS Applie	8.0	156
8	Highâ€Performance Topâ€Gated Grapheneâ€Nanoribbon Transistors Using Zirconium Oxide Nanowires as Highâ€Dielectricâ€Constant Gate Dielectrics. Advanced Materials, 2010, 22, 1941-1945.	21.0	132
9	A systematic study of atmospheric pressure chemical vapor deposition growth of large-area monolayer graphene. Journal of Materials Chemistry, 2012, 22, 1498-1503.	6.7	76
10	Growth of Nickel Silicides in Si and Si/SiOx Core/Shell Nanowires. Nano Letters, 2010, 10, 4721-4726.	9.1	74
11	Detection of Spin Polarized Carrier in Silicon Nanowire with Single Crystal MnSi as Magnetic Contacts. Nano Letters, 2010, 10, 2281-2287.	9.1	68
12	Rational Design and Synthesis of Freestanding Photoelectric Nanodevices as Highly Efficient Photocatalysts. Nano Letters, 2010, 10, 1941-1949.	9.1	62
13	The growth and applications of silicides for nanoscale devices. Nanoscale, 2012, 4, 1412-1421.	5.6	41
14	Kinetic Competition Model and Size-Dependent Phase Selection in 1-D Nanostructures. Nano Letters, 2012, 12, 3115-3120.	9.1	40
15	Kinetic Manipulation of Silicide Phase Formation in Si Nanowire Templates. Nano Letters, 2013, 13, 3703-3708.	9.1	33
16	Heterointegration of Pt/Si/Ag Nanowire Photodiodes and Their Photocatalytic Properties. Advanced Functional Materials, 2010, 20, 3005-3011.	14.9	28
17	The Influence of Surface Oxide on the Growth of Metal/Semiconductor Nanowires. Nano Letters, 2011, 11, 2753-2758.	9.1	23
18	Domain Wall Motion in Synthetic Co ₂ Si Nanowires. Nano Letters, 2012, 12, 1972-1976.	9.1	17

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#	Article	IF	CITATIONS
19	Self-Aligned Nanolithography in a Nanogap. Nano Letters, 2009, 9, 2234-2238.	9.1	15
20	Synthesis and electric properties of dicobalt silicide nanobelts. Chemical Communications, 2011, 47, 1255-1257.	4.1	15
21	Crystallinity Control of Ferromagnetic Contacts in Stressed Nanowire Templates and the Magnetic Domain Anisotropy. Nano Letters, 2012, 12, 4341-4348.	9.1	12
22	Laser Annealing of Pb(Zr0.52Ti0.48)O3 Thin Films Using Pulsed Excimer (KrF) Laser. Integrated Ferroelectrics, 2003, 52, 119-126.	0.7	1
23	PREPARATION OF HIGHLY TEXTURED ALN FILMS USING MO AND TI ELECTRODE FOR INTEGRATED ALN-BASED FILM BULK ACOUSTIC WAVE RESONATORS. Integrated Ferroelectrics, 2006, 80, 407-413.	0.7	1
24	Low Temperature Synthesis of AlN Films by ICP-Assisted Metalorganic Chemical Vapor Deposition Method. Integrated Ferroelectrics, 2004, 68, 95-103.	0.7	0
25	Heterointegration of Pt/Si/Ag Nanowire Photodiodes and Their Photocatalytic Properties. Advanced Functional Materials, 2010, 20, n/a-n/a.	14.9	0
26	Nanoelectronic Devices from Nanowire Heterostructures. ECS Transactions, 2010, 33, 3-11.	0.5	0